Series One is a direct outgrowth of our research into Series Three, the world’s most advanced professional power amplifiers. Series One fills the bill for those discriminating users who demand superior audio performance but don’t require low profile chassis, front removable channel modules, calibrated gain controls, or true dual monaural configuration. As a result of our development of the QSC full feature Series Three amps, Series One benefits from our time proven circuitry combined with our latest design techniques and components.

The Model 1200 is a medium power stereo amplifier designed for professional and commercial applications requiring both high performance and high reliability. Sharing a common chassis and circuit board with our Model 1400, this lower powered, passively cooled version is loaded with useful features and benefits. Compare it to any product available. You’ll find that it’s exceede only by our own Series Three.

FEATURES:

- High performance, full complementary circuit.
- Independent DC and sub audio speaker protection on each channel.
- Calibrated gain controls.
- Active balanced inputs.
- Octal input sockets for accessory modules such as crossovers, limiters, and transformers.
- Mono-bridging switch.
- 1/4” RTS, XLR, and barrier strip input connectors.
- Patented Output Averaging™ short-circuit protection.
- Clipping indicators.
- Passive cooling.
- Optional fan cooling.
- Direct mounted power transistors.
- 3 year warranty
MODEL 1200 SPECIFICATIONS

OUTPUT POWER (per channel):
Continuous Average Output Power both channels driven:
8 ohms, 20 Hz–20 kHz, 0.1% THD 100 watts
4 ohms, 20 Hz–20 kHz, 0.1% THD 150 watts
Continuous Average Output Power one channel driven:
8 ohms, 1 kHz, 1% THD 130 watts
4 ohms, 1 kHz, 1% THD 200 watts
2 ohms, 1 kHz, 1% THD 250 watts ± 1 dB
Continuous Average Output Power bridged mono operation:
16 ohms, 20 Hz–20 kHz, 0.1% THD 220 watts
8 ohms, 20 Hz–20 kHz, 0.1% THD 300 watts

DISTORTION (8 ohms):
THD: 20 Hz–20 kHz at rated power shall be less than 0.1%.
SMpte/IM distortion less than 0.025% at rated power.

FREQUENCY RESPONSE:
20 Hz–20 kHz ± 0.5 dB at 1 watt.

POWER BANDWIDTH:
5 Hz to 60 kHz.

SLEW RATE:
12 V/μs.

DAMPING FACTOR:
200 at 8 ohms.

DYNAMIC HEADROOM:
2 dB at 8 ohms.

NOISE:
– 100 dB below full output, A weighted.
SENSITIVITY:
With gain control at maximum, 29 dB voltage gain. 1.00 Vrms for rated power at 8 ohms.

INPUT IMPEDANCE:
20 kΩohms balanced and unbalanced noninverting or 10 kΩohms unbalanced inverting.

POWER REQUIREMENTS:
110–25 Vac, 60 Hz.

POWER CONSUMPTION:
4.4 Aac at 120 V.

DIMENSIONS:
5.25’’ tall (three rack spaces), 19’’ wide, 9.5’’ deep.

WEIGHT:
24 lb net, 28 lb shipping weight.

ARCHITECTS AND ENGINEERS SPECIFICATIONS:

The power amplifier shall contain all solid-state circuitry, using complementary silicon semiconductors. It shall be capable of operating from 110–125 Vac, 60 Hz.

The amplifier shall contain two independent channels. Each channel shall have independent protective circuitry against open circuit, short circuit, or reactive loads, and the remaining channel shall continue to operate if one channel fails. A muting circuit shall provide three seconds of muting after turn-on, and shall mute within 1/4 second after turn-off or loss of power, to protect the load against turn-on or turn-off thumps. Self resetting thermal shutdown shall protect the circuitry against temperatures in excess of 90°C, and a front panel resettable circuit breaker shall protect against AC overloads.

Each channel of the amplifier shall be capable of meeting the following performance criteria, with both channels driven simultaneously unless otherwise stated: Output power, 8 ohms per channel, 20 Hz–20 kHz, less than 0.1% distortion, at least 100 watts rms per channel. Output power, 4 ohms per channel, 20 Hz–20 kHz, less than 0.1% distortion, at least 150 watts rms per channel. Output power, single channel driven, 4 ohms, 1 kHz, less than 1% clipping, at least 200 watts rms.

Frequency response shall be 20 Hz–20 kHz ± 0.5 dB at 1 watt output. SMPTE IM distortion shall be less than 0.025% at rated power, 8 ohms, and less than 0.05% at rated power, 4 ohms. IHF damping factor shall be at least 200. Signal to noise, below rated output, shall be at least 100 dB (A weighted). Dynamic headroom at 8 ohms shall be at least 2 dB. The voltage gain shall be 29 dB at full gain. The input sensitivity for rated 8 ohm power shall be 1 Vrms. Balanced input impedance shall be 20 kΩohms balanced and unbalanced noninverting, 10 kΩohms unbalanced inverting. Balanced, bridging input circuitry shall be standard, and the amplifier shall meet all performance criteria in the balanced or unbalanced mode. The amplifier shall have convection cooling, with provision for optional built-in fan cooling. If the fan option is used, air flow shall be from the back to the front. Each channel shall have the following controls, indicators, and connectors: Front mounted gain control calibrated in dB. Clipping indicator, responding proportionally to any distortion in excess of 0.1%. Balanced/unbalanced input jack of the 1/4” ring, tip, sleeve type (tip inverting). Balanced input jack of the XLR type. Balanced input of the barrier strip screw terminal type. Octal accessory socket with DC power for active and passive input accessories. 8-position microphone switches for bypassing the octal sockets, paralleling the two channels, and assigning a single octal accessory to both channels. Speaker terminals of the 5 way binding post type. In addition, the chassis shall feature a rear mounted mono-bridging switch, front mounted AC switch and circuit breaker, mounting positions on the rear for optional 70 V output transformers, and built-in rack mounting ears. The chassis shall mount in a 19” rack, occupying 3 rack spaces (5.25”). Chassis depth behind the rails shall be 8.5” plus 1” allowance for the binding posts. The front protrusion shall be 1/4” unless optional 3.75” handles are installed. Weight shall be 24 lb. The amplifier shall be the QSC Model 1200.